

## Transistors

## 2.5V Drive Pch MOS FET

## RTE002P02

## ●Structure

Silicon P-channel MOS FET

## ●Features

- 1) Low On-resistance.
- 2) Small package (EMT3).
- 3) 2.5V drive.

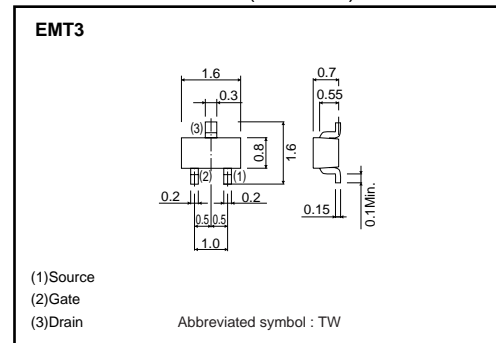
## ●Applications

Switching

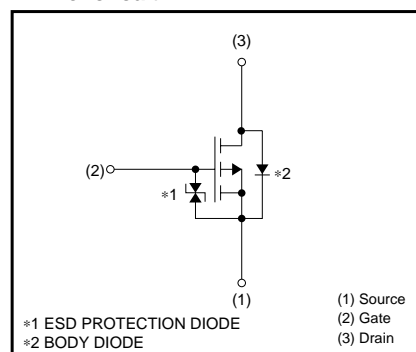
## ●Package specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
RTE002P02		○

## ●External dimensions (Unit : mm)



## ●Inner circuit



## ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	$V_{DSS}$	-20	V	
Gate-source voltage	$V_{GSS}$	±12	V	
Drain current	Continuous	$I_D$	±0.2	A
	Pulsed	$I_{DP}$ *1	±0.4	A
Total power dissipation	$P_D$ *2	0.15	W	
Channel temperature	$T_{ch}$	150	°C	
Range of storage temperature	$T_{stg}$	-55 to +150	°C	

\*1  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$ 

\*2 Each terminal mounted on a recommended land

## ●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th}(ch-a)$ *	833	°C/W

\* Each terminal mounted on a recommended land

## Transistors

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	–	–	±10	μA	$V_{GS} = \pm 12V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	–20	–	–	V	$I_D = -1mA, V_{GS} = 0V$
Zero gate voltage drain current	$I_{DSS}$	–	–	–1	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	–0.7	–	–2.0	V	$V_{DS} = -10V, I_D = -1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	–	1.0	1.5	Ω	$I_D = -0.2A, V_{GS} = -4.5V$
		–	1.1	1.6	Ω	$I_D = -0.2A, V_{GS} = -4V$
		–	2.0	3.0	Ω	$I_D = -0.15A, V_{GS} = -2.5V$
Forward transfer admittance	$ Y_{fs} $ *	0.2	–	–	S	$V_{DS} = -10V, I_D = -0.15A$
Input capacitance	$C_{iss}$	–	50	–	pF	$V_{DS} = -10V$
Output capacitance	$C_{oss}$	–	5	–	pF	$V_{GS} = 0V$
Reverse transfer capacitance	$C_{rss}$	–	5	–	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}$ *	–	9	–	ns	$V_{DD} = -15V$
Rise time	$t_r$ *	–	6	–	ns	$I_D = -0.15A$
Turn-off delay time	$t_{d(off)}$ *	–	35	–	ns	$V_{GS} = -4.5V$
Fall time	$t_f$ *	–	45	–	ns	$R_L = 100\Omega$ $R_G = 10\Omega$

\*Pulsed

## ●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	$V_{SD}$	–	–	–1.2	V	$I_S = -0.1A, V_{GS} = 0V$

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